

**CCG30-24-\*\*D**

**EVALUATION DATA**

型式データ

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## 使用記号 Terminology used

	定義	Definition
$V_{in}$	.....	入力電圧 Input voltage
$+V_o, -V_o$	.....	出力電圧 Output voltage
$V_{rc}$	.....	RC電圧 RC voltage
$I_{in}$	.....	入力電流 Input current
$+I_o, -I_o$	.....	出力電流 Output current
$T_a$	.....	周囲温度 Ambient temperature
$f$	.....	周波数 Frequency

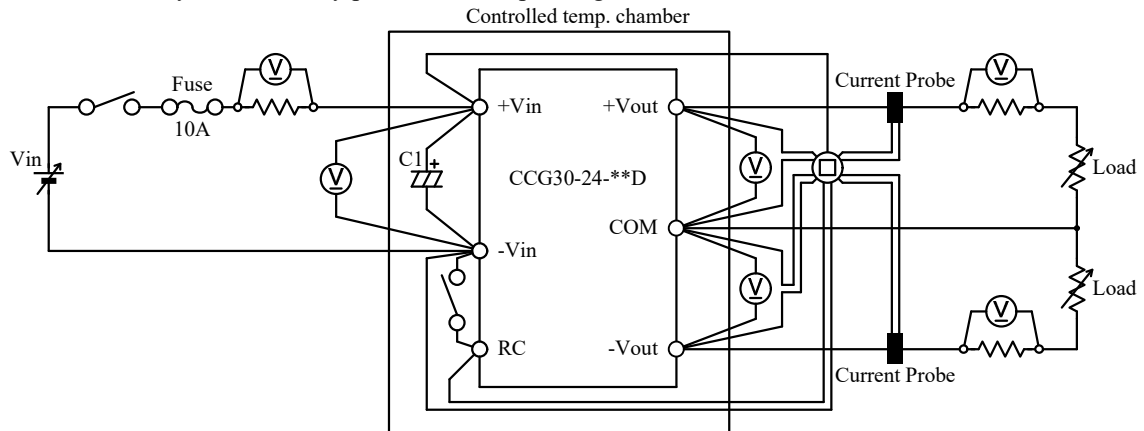
※ 当社測定条件における結果であり、参考値としてお考え願います。  
Test results are reference data based on our measurement condition.

1. 測定方法 Evaluation Method

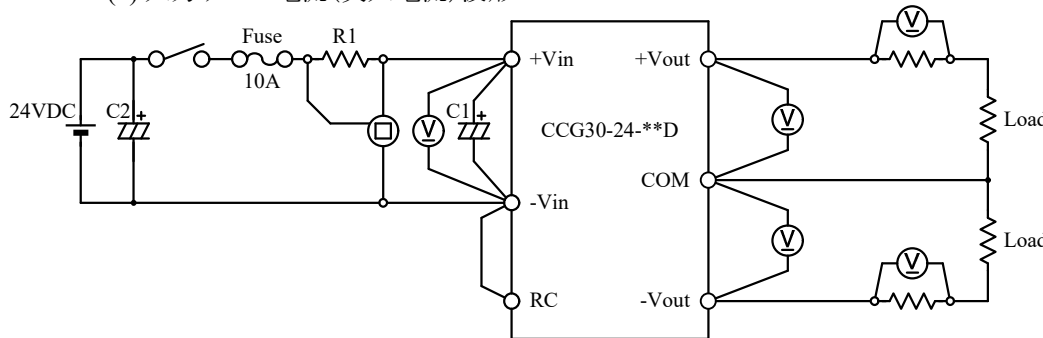
1-1. 測定回路 Measurement Circuits

(1) 静特性、待機電力特性、通電ドリフト特性、その他特性

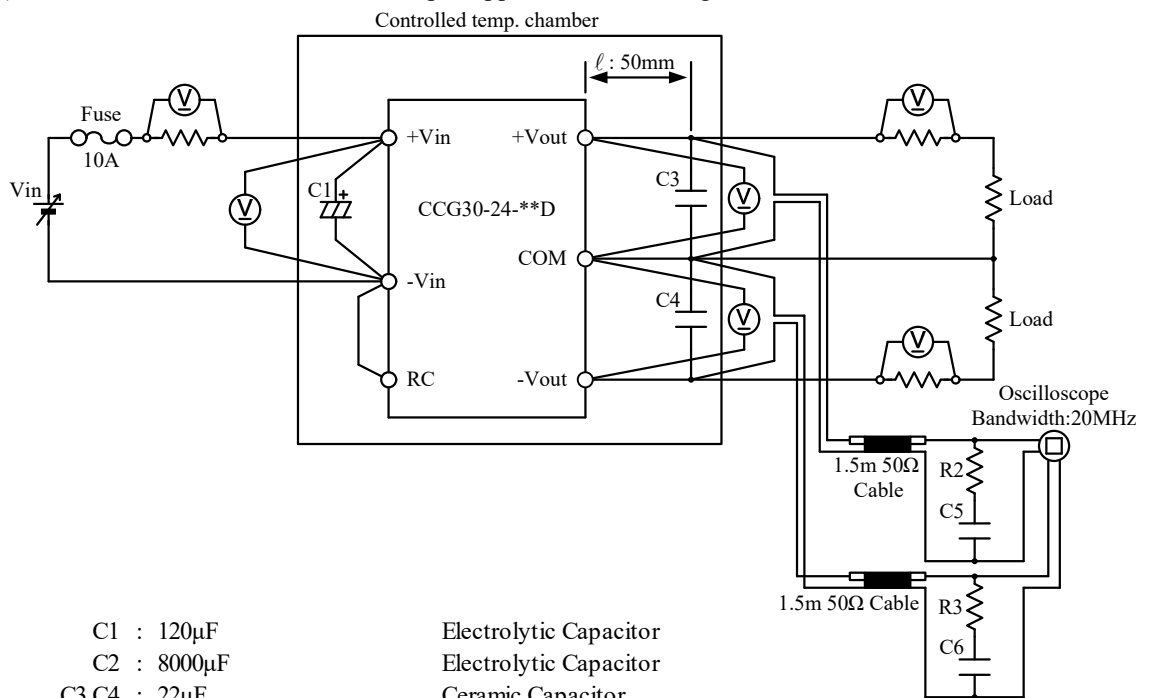
Steady state, Standby power, Warm up voltage drift and Other characteristics



(2) 入力サージ電流(突入電流)波形 Inrush current waveform



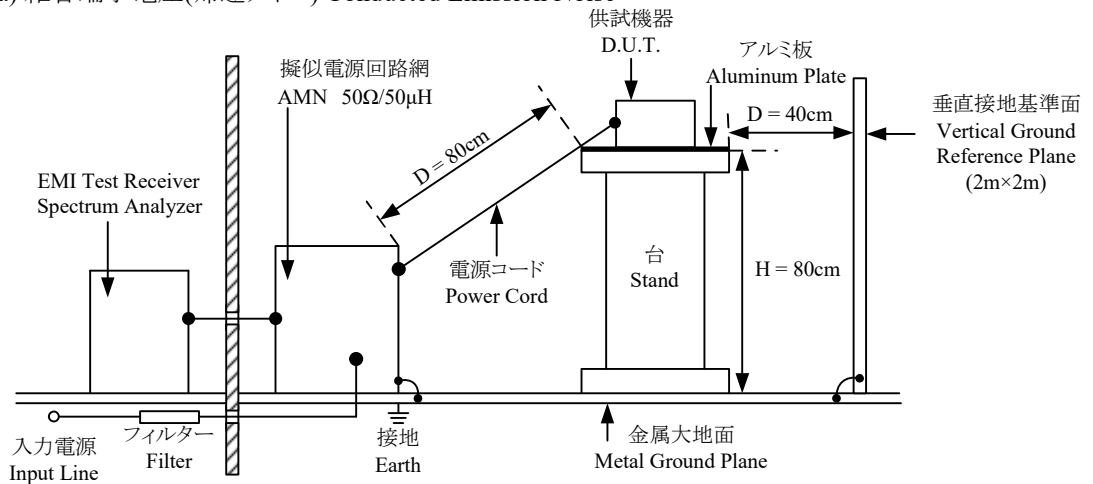
(3) 出力リップル、ノイズ電圧、波形 Output ripple and noise voltage and waveform



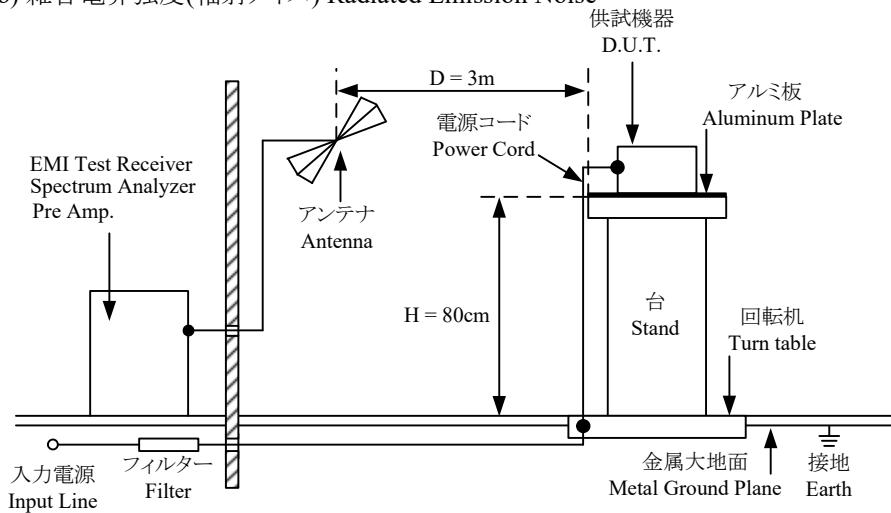
- C1 : 120 $\mu$ F Electrolytic Capacitor
- C2 : 8000 $\mu$ F Electrolytic Capacitor
- C3,C4 : 22 $\mu$ F Ceramic Capacitor
- C5,C6 : 4700pF Ceramic Capacitor
- R1 : 0.01 $\Omega$
- R2,R3 : 50 $\Omega$

(4) EMI特性 Electro-Magnetic Interference characteristics

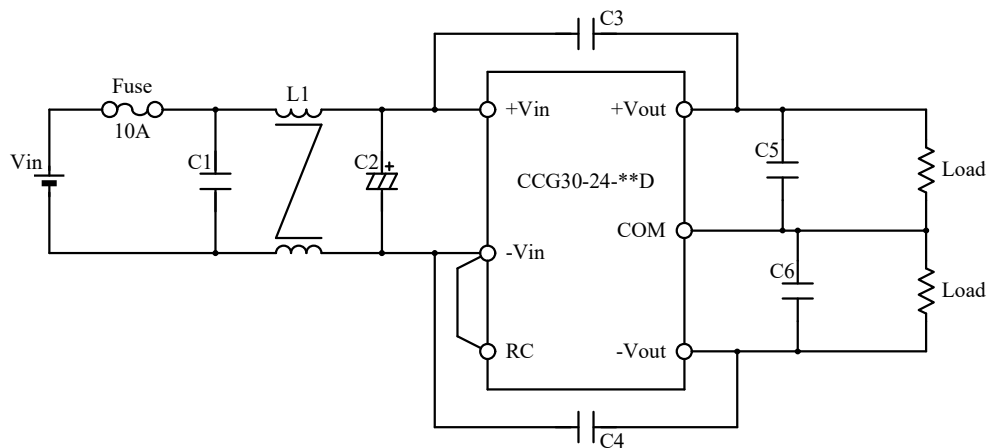
(a) 雑音端子電圧(帰還ノイズ) Conducted Emission Noise



(b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



VCCI class A 対応アプリケーション VCCI class A application system



- |                            |                        |
|----------------------------|------------------------|
| C1 : 10μF                  | Ceramic Capacitor      |
| C2 : 120μF                 | Electrolytic Capacitor |
| C3,C4 : 1000pF×2parallel   | Ceramic Capacitor      |
| C5,C6 : 22μF               | Ceramic Capacitor      |
| L1 : ACM1211-102-2PL (TDK) | Common Mode Choke Coil |

## 1-2. 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL1740 / DL1740E
2	DIGITAL MULTIMETER	AGILENT	34970A
3	CURRENT PROBE	YOKOGAWA ELECT.	701932
4	CURRENT PROBE	AGILENT	N2774A
5	SHUNT RESISTER	YOKOGAWA ELECT.	2215
6	DYNAMIC DUMMY LOAD	TAKASAGO	FK-200L / FK-600L
7	CVCF	TAKASAGO	AA2000XG
8	CVCF	NF	ES1000S / ES10000S
9	DC POWER SUPPLY	TDK-Lambda	Z+100-8
10	CONTROLLED TEMP. CHAMBER	ESPEC	SU-261 / SU-641
11	EMI TEST RECEIVER / SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESCI
12	PRE AMP.	SONOMA	310N
13	AMN	KIKUSUI	KNW-242C
14	ANTENNA	SCHWARZBECK	BBA9106/VHA9103
15	ANTENNA	SCHWARZBECK	UHALP9107

## 2. 特性データ Characteristics

### 2-1. 静特性 Steady state characteristics

#### (1) 入力・負荷・温度変動 Regulation - line and load, Temperature drift

±12V

## 1. Regulation - line and load

Condition Ta : 25 °C

• +Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	12.078V	12.079V	12.078V	12.079V	1mV	0.008%
50%	12.076V	12.077V	12.077V	12.076V	1mV	0.008%
100%	12.066V	12.075V	12.082V	12.081V	16mV	0.133%
Load	12mV	4mV	5mV	5mV		
regulation	0.100%	0.033%	0.042%	0.042%		

• -Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	-12.094V	-12.095V	-12.096V	-12.094V	2mV	0.017%
50%	-12.093V	-12.093V	-12.092V	-12.092V	1mV	0.008%
100%	-12.102V	-12.094V	-12.087V	-12.085V	17mV	0.142%
Load	9mV	2mV	9mV	9mV		
regulation	0.075%	0.017%	0.075%	0.075%		

• +Vo to -Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	24.171V	24.173V	24.174V	24.174V	3mV	0.025%
50%	24.169V	24.170V	24.169V	24.169V	1mV	0.008%
100%	24.167V	24.169V	24.170V	24.166V	4mV	0.033%
Load	4mV	4mV	5mV	8mV		
regulation	0.033%	0.033%	0.042%	0.067%		

## 2. Temperature drift

Conditions Vin : 24 VDC  
Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability	
+Vo	12.078V	12.082V	12.098V	20mV	0.167%
-Vo	-12.071V	-12.087V	-12.106V	35mV	0.292%
+Vo to -Vo	24.149V	24.170V	24.204V	55mV	0.458%

## 3. Load Regulation - Unbalance load

Conditions Ta : 25 °C

• -Io : 100%

+Io \ Vin	9VDC	12VDC	24VDC	36VDC
20%	12.219V	12.214V	12.215V	12.213V
100%	12.071V	12.081V	12.087V	12.084V
Load	148mV	133mV	128mV	129mV
regulation	1.233%	1.108%	1.067%	1.075%

• +Io : 100%

-Io \ Vin	9VDC	12VDC	24VDC	36VDC
20%	-12.278V	-12.274V	-12.271V	-12.268V
100%	-12.106V	-12.096V	-12.089V	-12.087V
Load	172mV	178mV	182mV	181mV
regulation	1.433%	1.483%	1.517%	1.508%

$\pm 15V$ 

## 1. Regulation - line and load

Condition Ta : 25 °C

• +Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	15.101V	15.102V	15.102V	15.100V	2mV	0.013%
50%	15.095V	15.096V	15.095V	15.094V	2mV	0.013%
100%	15.096V	15.096V	15.096V	15.092V	4mV	0.027%
Load regulation	6mV	6mV	7mV	8mV		
	0.040%	0.040%	0.047%	0.053%		

• -Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	-15.089V	-15.091V	-15.090V	-15.090V	2mV	0.013%
50%	-15.092V	-15.094V	-15.092V	-15.091V	3mV	0.020%
100%	-15.090V	-15.092V	-15.093V	-15.089V	4mV	0.027%
Load regulation	3mV	3mV	3mV	2mV		
	0.020%	0.020%	0.020%	0.013%		

• +Vo to -Vo

Io \ Vin	9VDC	12VDC	24VDC	36VDC	Line regulation	
0%	30.190V	30.193V	30.192V	30.189V	4mV	0.027%
50%	30.187V	30.190V	30.187V	30.184V	6mV	0.040%
100%	30.186V	30.188V	30.188V	30.181V	7mV	0.047%
Load regulation	4mV	5mV	5mV	8mV		
	0.027%	0.033%	0.033%	0.053%		

## 2. Temperature drift

Conditions Vin : 24 VDC  
Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability	
+Vo	15.088V	15.096V	15.121V	33mV	0.220%
-Vo	-15.088V	-15.093V	-15.116V	28mV	0.187%
+Vo to -Vo	30.176V	30.188V	30.237V	61mV	0.407%

## 3. Load Regulation - Unbalance load

Conditions Ta : 25 °C

• -Io : 100%

+Io \ Vin	9VDC	12VDC	24VDC	36VDC
20%	15.262V	15.257V	15.258V	15.254V
100%	15.107V	15.106V	15.105V	15.101V
Load regulation	155mV	151mV	153mV	153mV
	1.033%	1.007%	1.020%	1.020%

• +Io : 100%

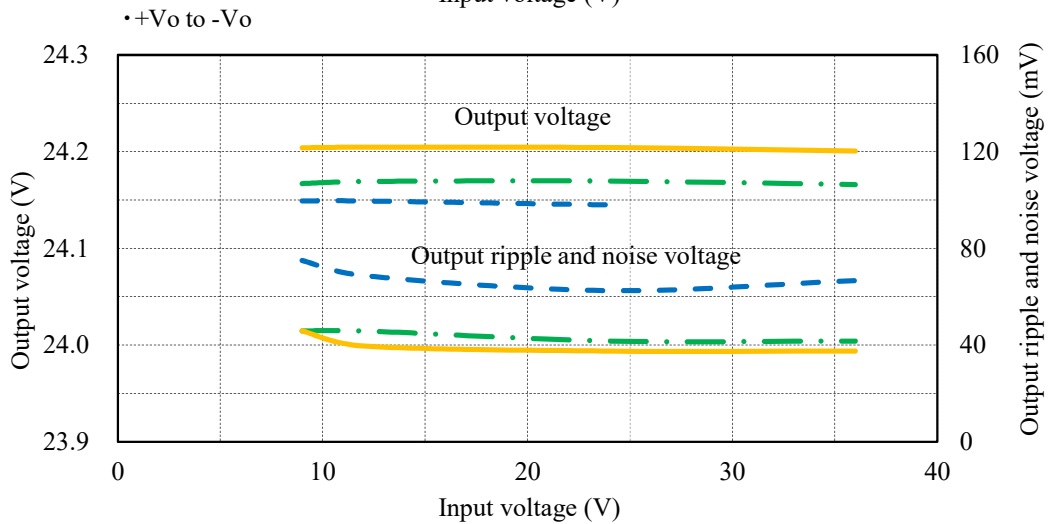
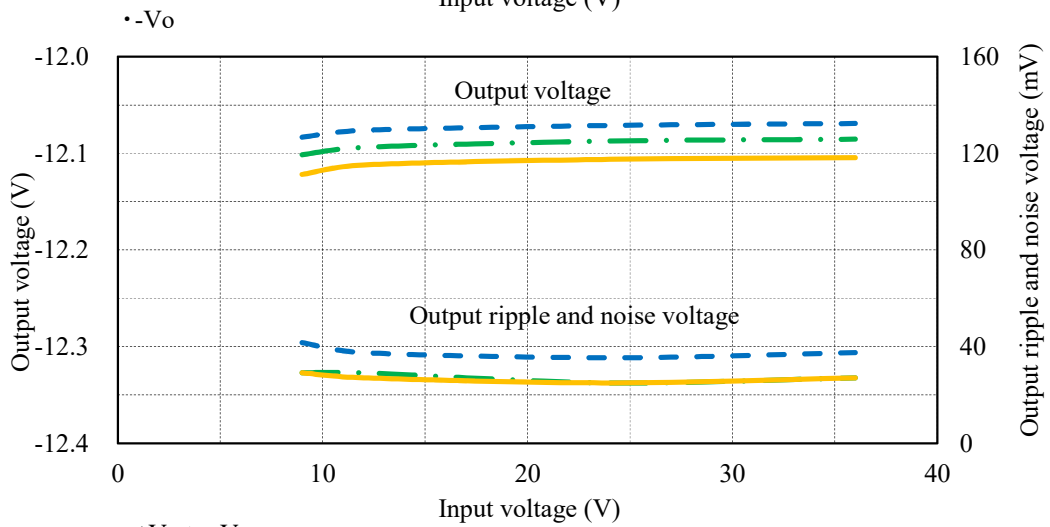
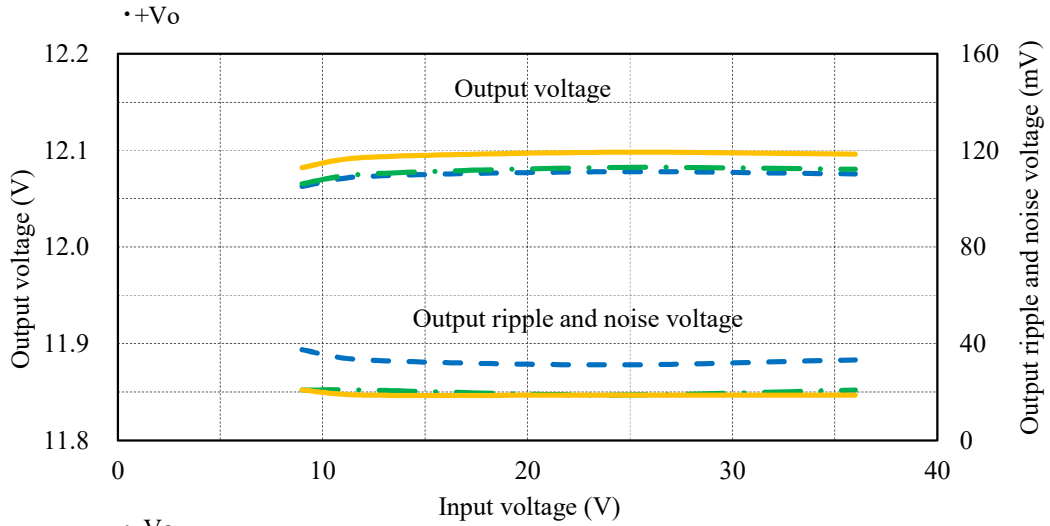
-Io \ Vin	9VDC	12VDC	24VDC	36VDC
20%	-15.246V	-15.246V	-15.246V	-15.241V
100%	-15.098V	-15.101V	-15.102V	-15.098V
Load regulation	148mV	145mV	144mV	143mV
	0.987%	0.967%	0.960%	0.953%

(2) 出力電圧・出力リップルノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

Conditions Io : 100 %  
 Ta : -40 °C ---  
 : 25 °C -.-  
 : 85 °C —

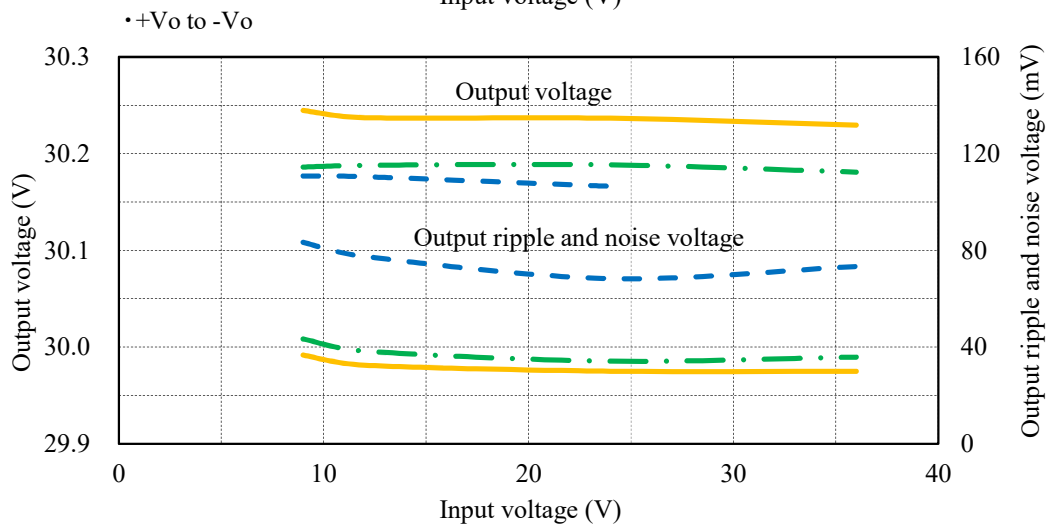
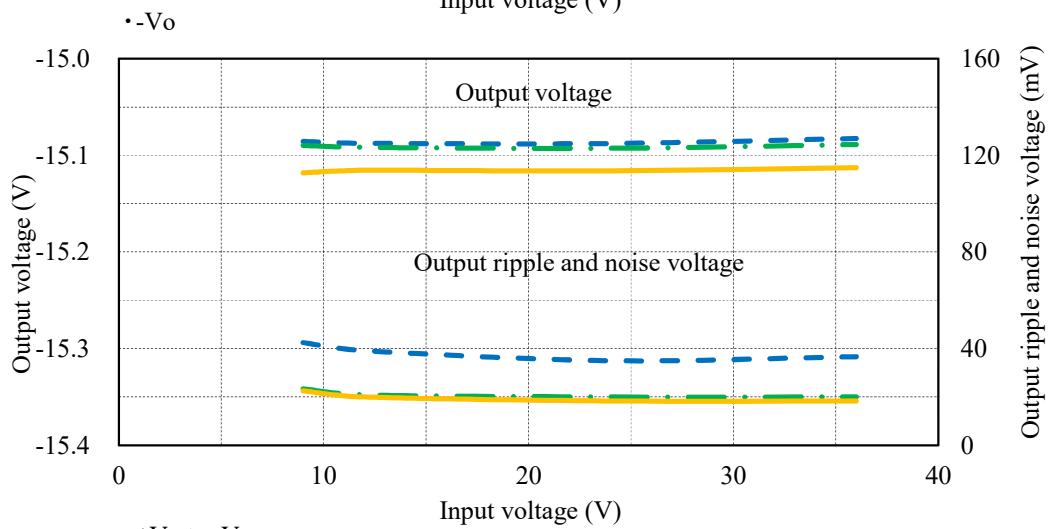
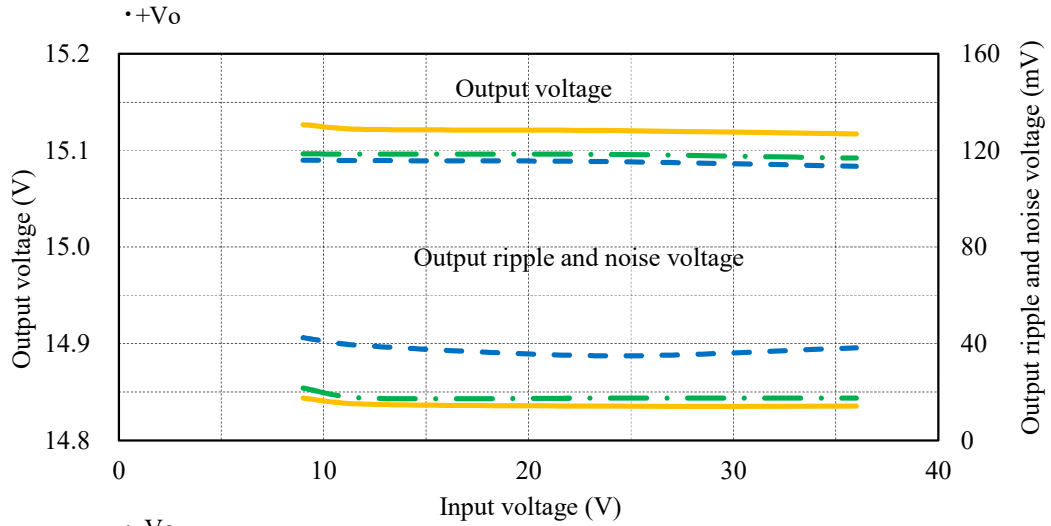
±12V





Conditions Io : 100 %  
 Ta : -40 °C  
 : 25 °C  
 : 85 °C

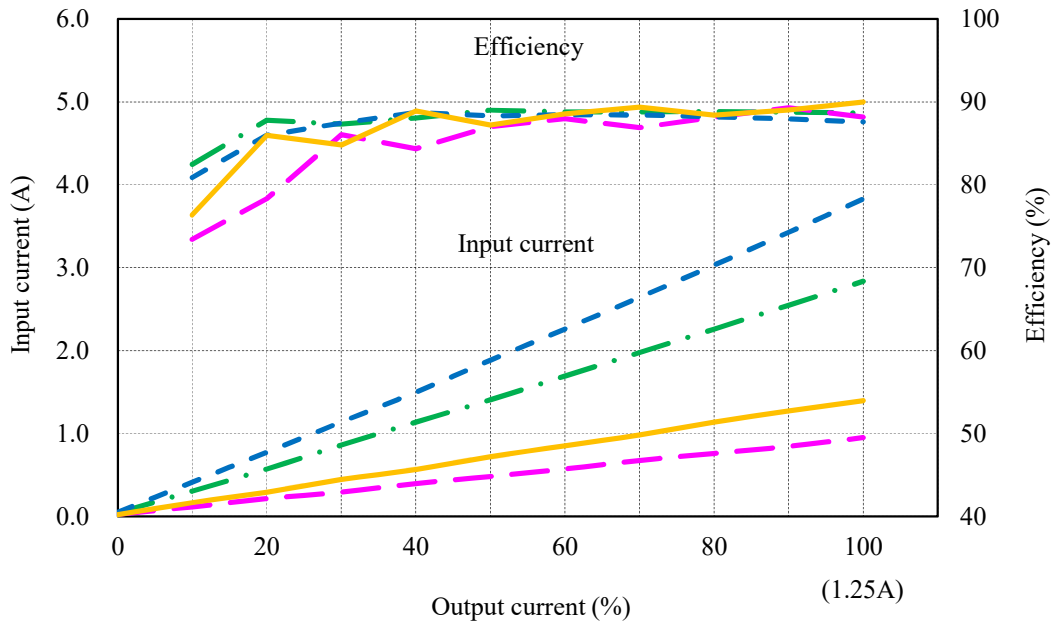
±15V



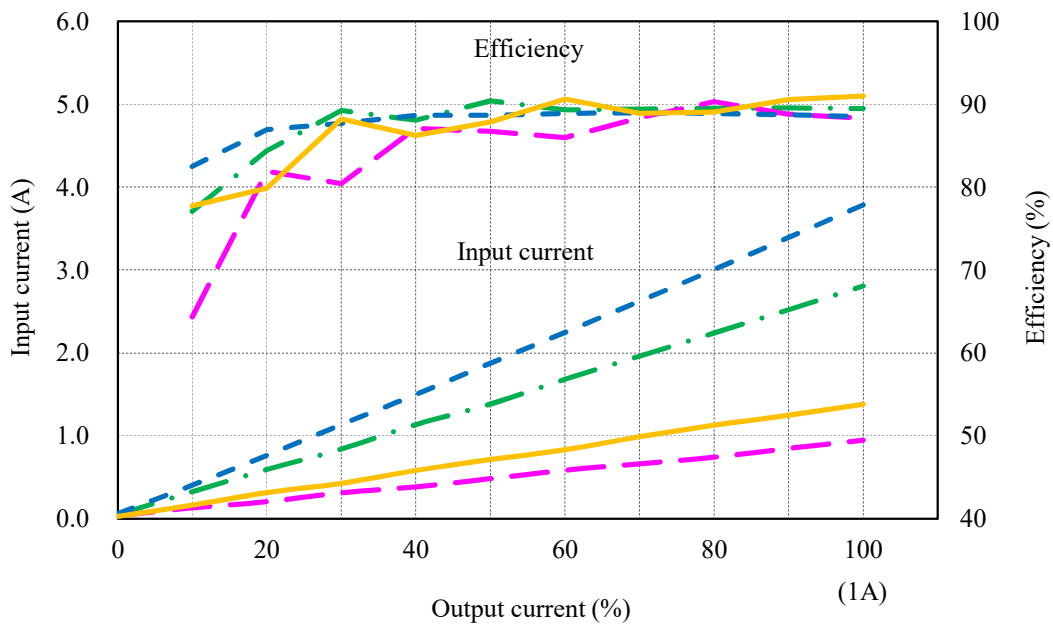
(3) 入力電流・効率 対 出力電流 Input current and Efficiency vs. Output current

Conditions Vin : 9 VDC ---  
 : 12 VDC -.-  
 : 24 VDC —  
 : 36 VDC - - -  
 Ta : 25 °C

±12V



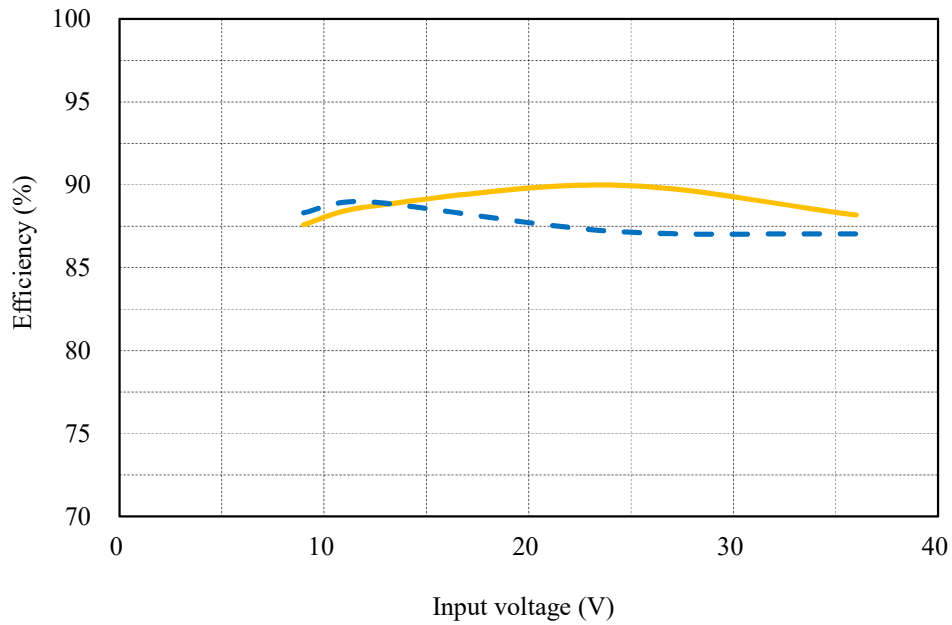
±15V



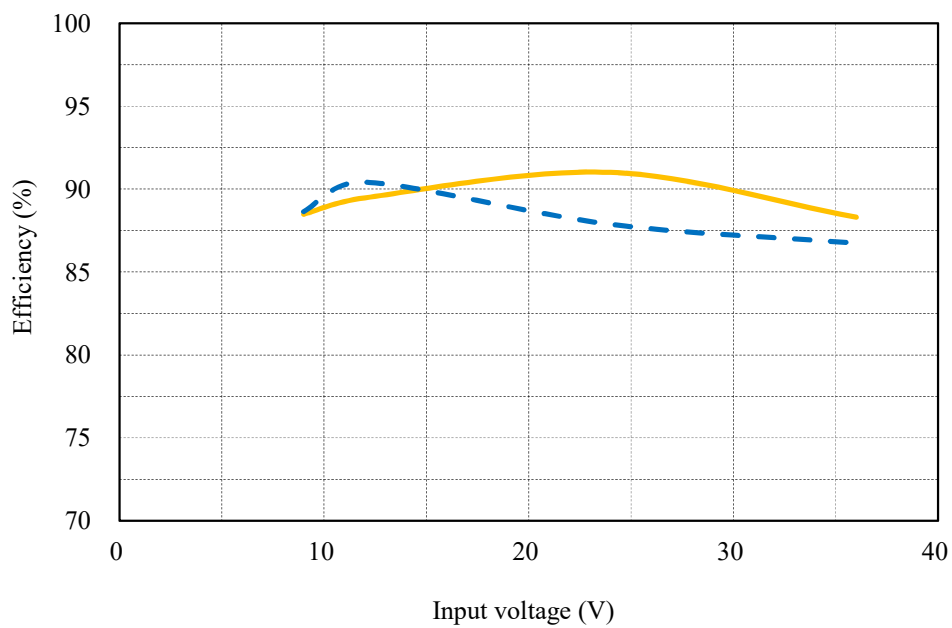
(4) 効率 対 入力電圧 Efficiency vs. Input voltage

Conditions Io : 50 % ---  
 : 100 % —  
 Ta : 25 °C

±12V



±15V



(5) 起動・遮断電圧特性 Start up and Drop out voltage characteristics

出力電圧 対 入力電圧

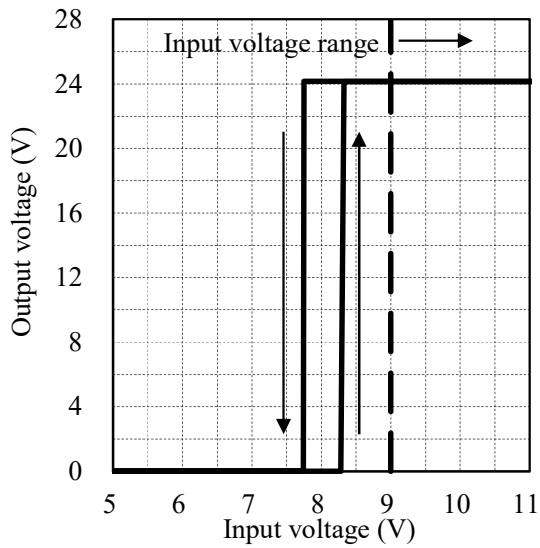
Output voltage vs. Input voltage

入力電流 対 入力電圧

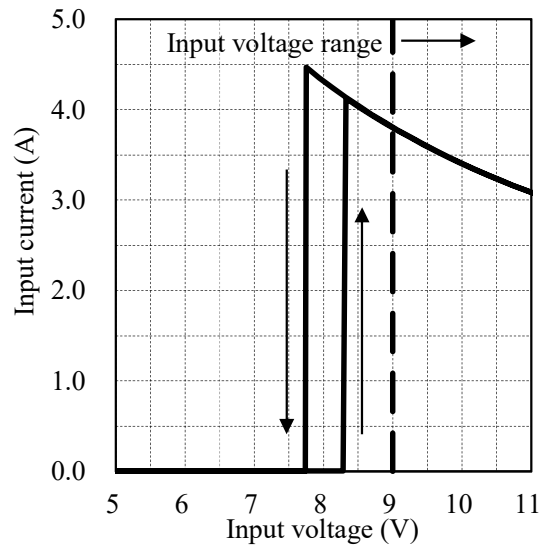
Input current vs. Input voltage

Conditions  $I_o$  : 100 %  
 $T_a$  : 25 °C

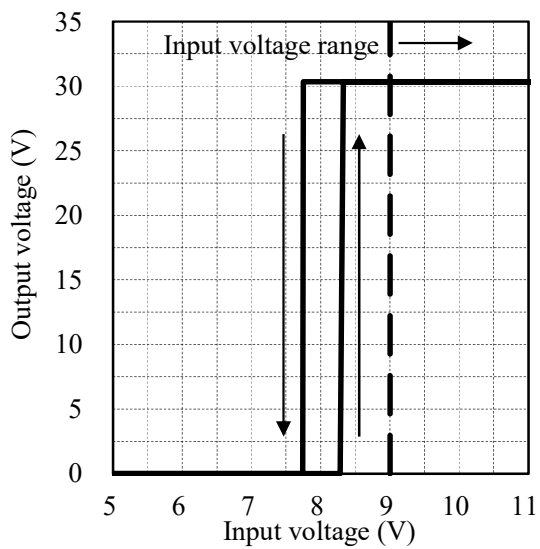
±12V



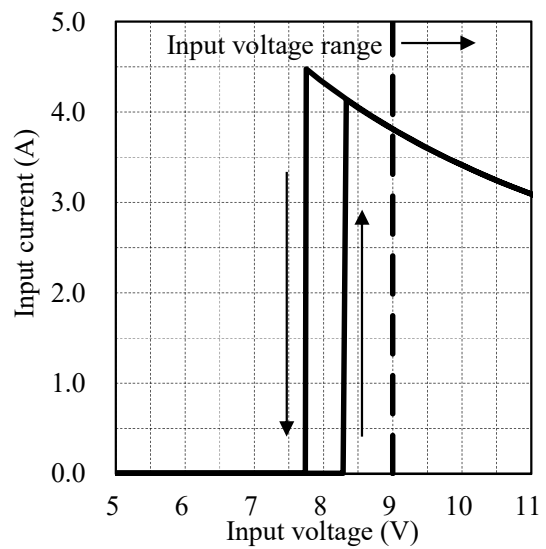
±12V



±15V



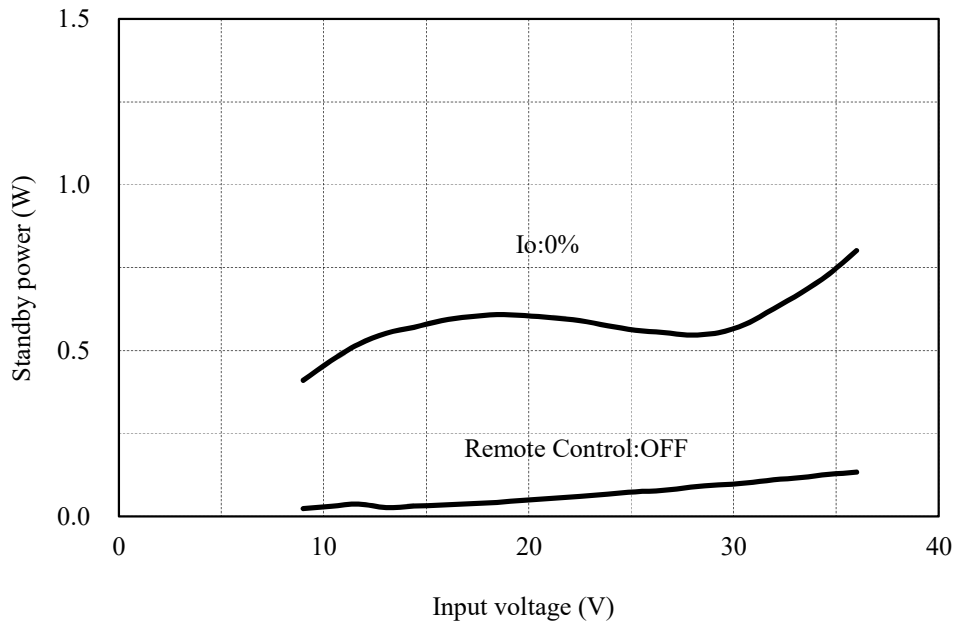
±15V



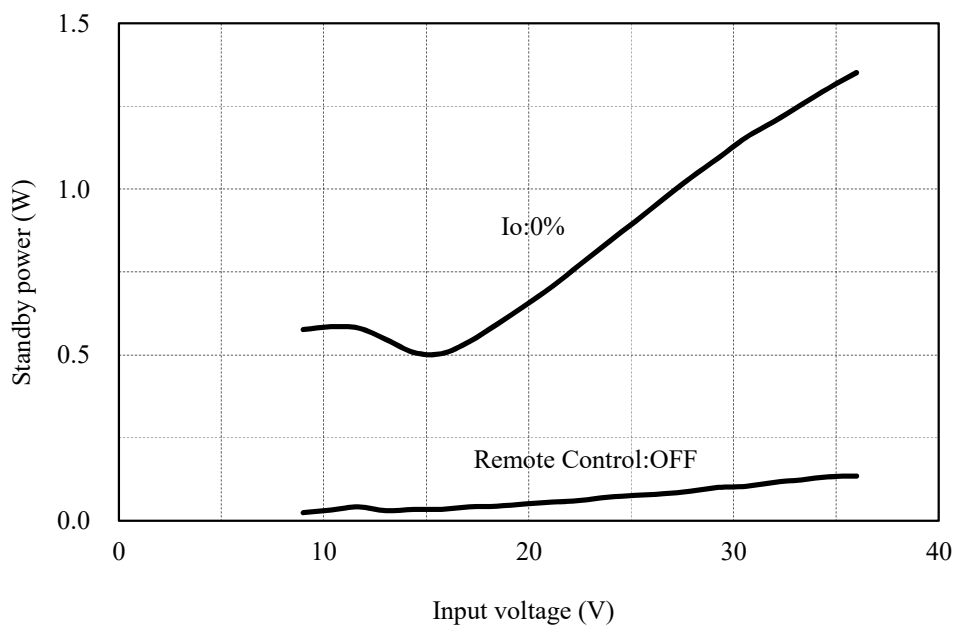
2-2. 待機電力特性 Standby power characteristics

Conditions Ta : 25 °C

±12V



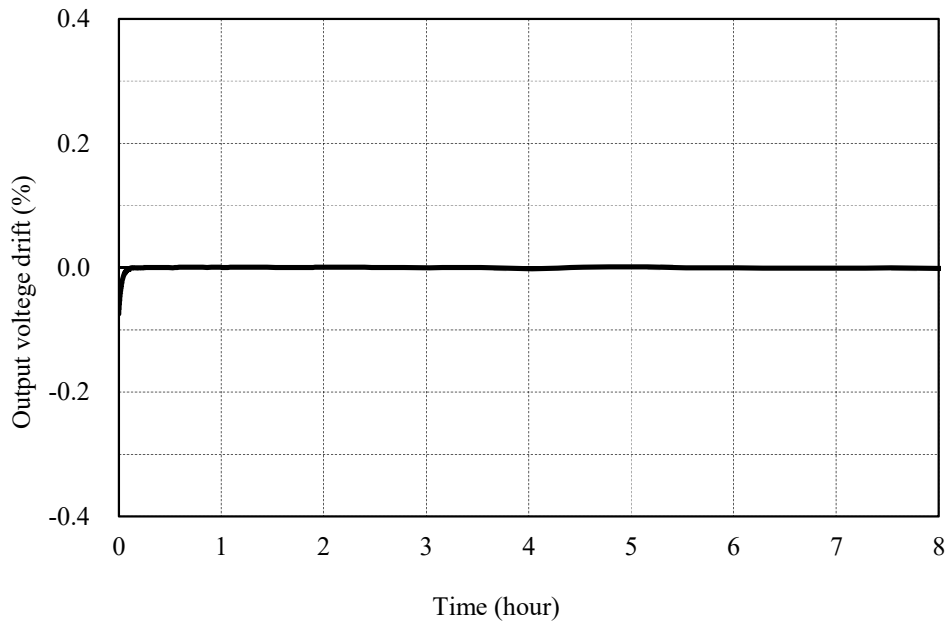
±15V



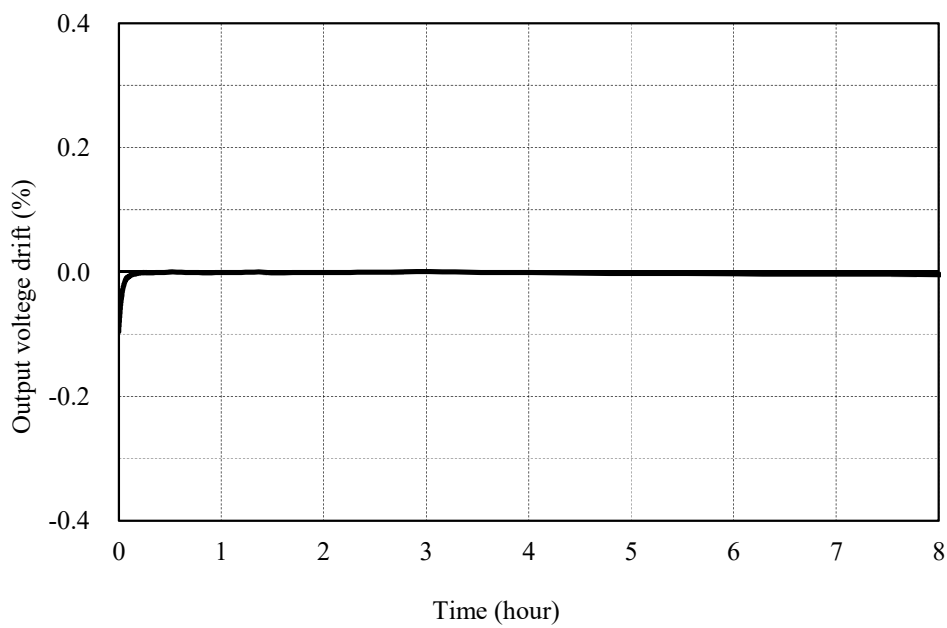
2-3. 通電ドリフト特性 Warm up voltage drift characteristics

Conditions Vin : 24 VDC  
 Io : 100 %  
 Ta : 25 °C

±12V



±15V



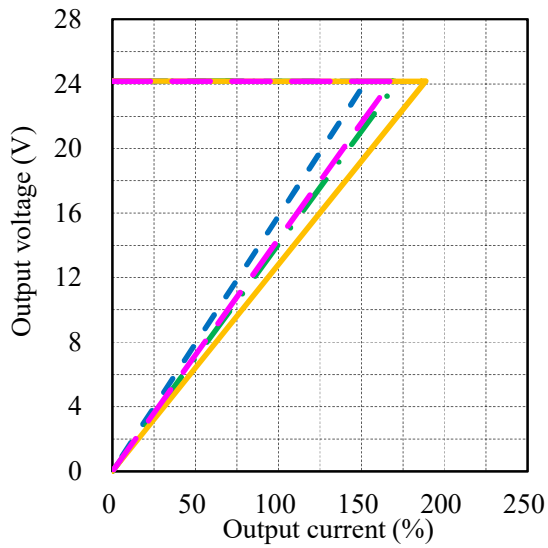
2-4. 過電流保護特性 Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

Conditions Vin : 9 VDC ---  
 : 12 VDC - · -  
 : 24 VDC —  
 : 36 VDC - - -  
 Ta : 25 °C

±12V

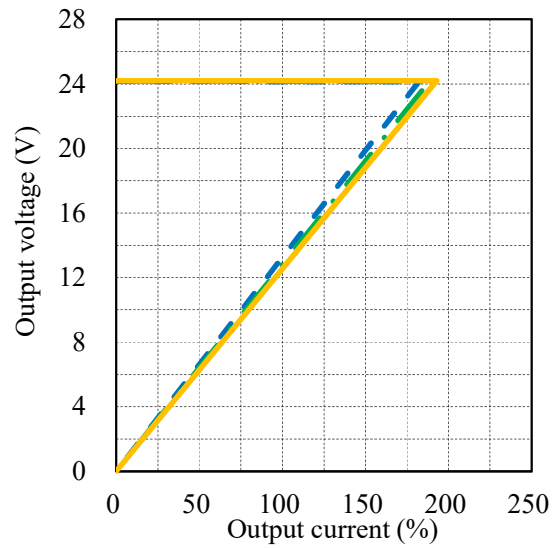


周囲温度依存性

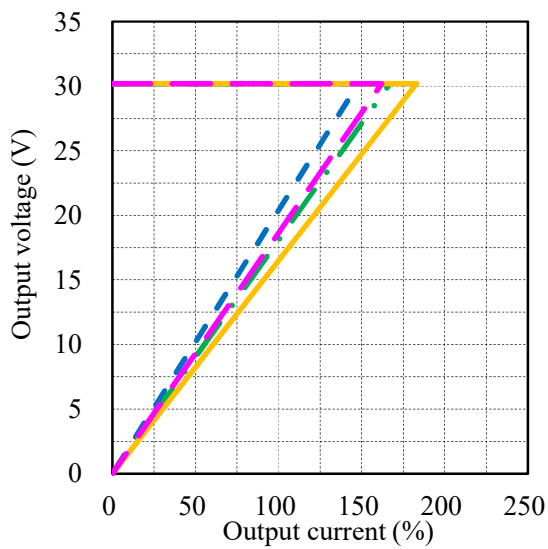
Ambient temperature dependence

Conditions Vin : 24 VDC  
 Ta : -40 °C ---  
 : 25 °C - · -  
 : 85 °C —

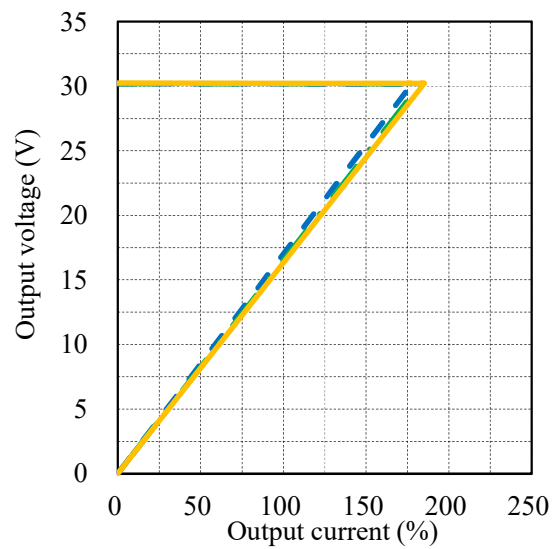
±12V



±15V



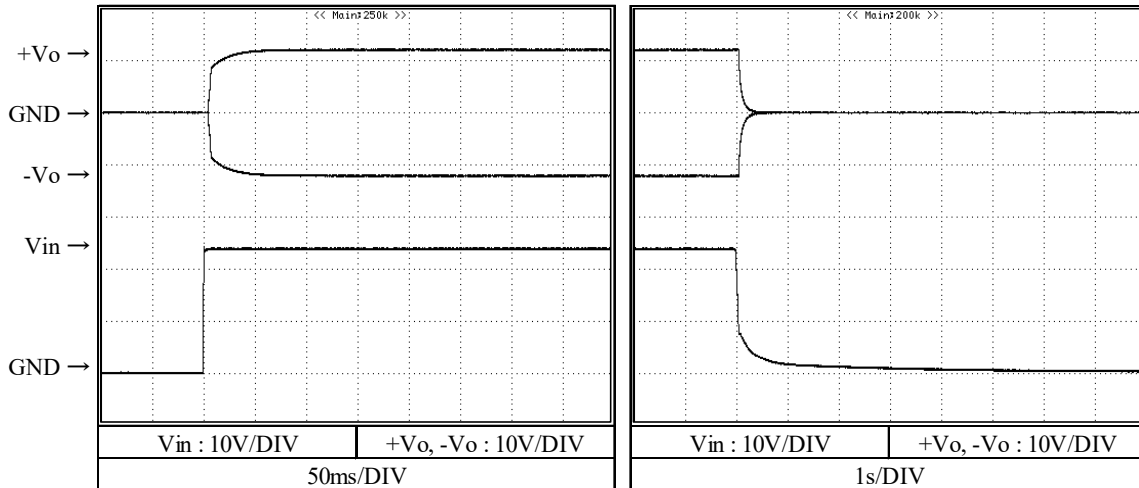
±15V



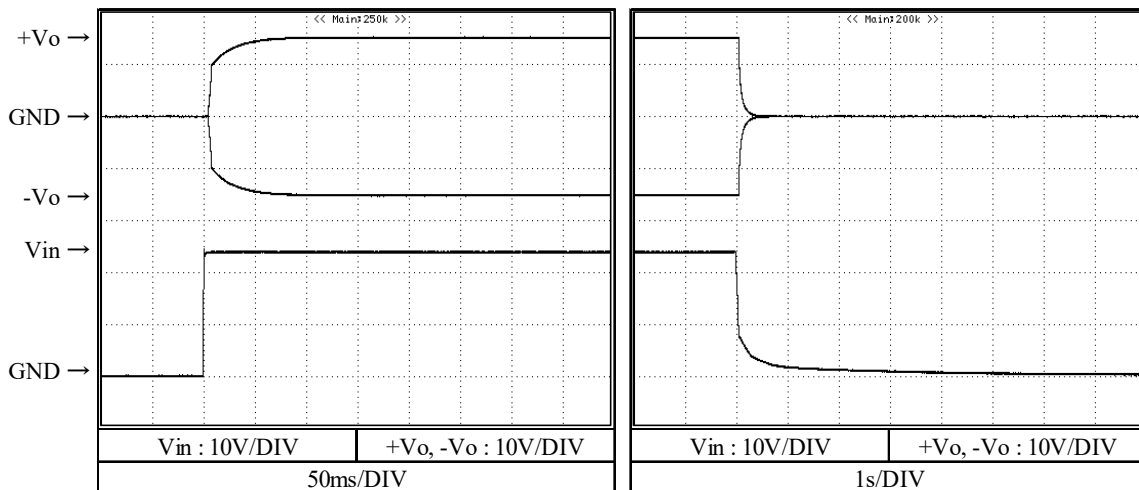
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 24 VDC  
 Io : 0 %  
 Ta : 25 °C

±12V



±15V

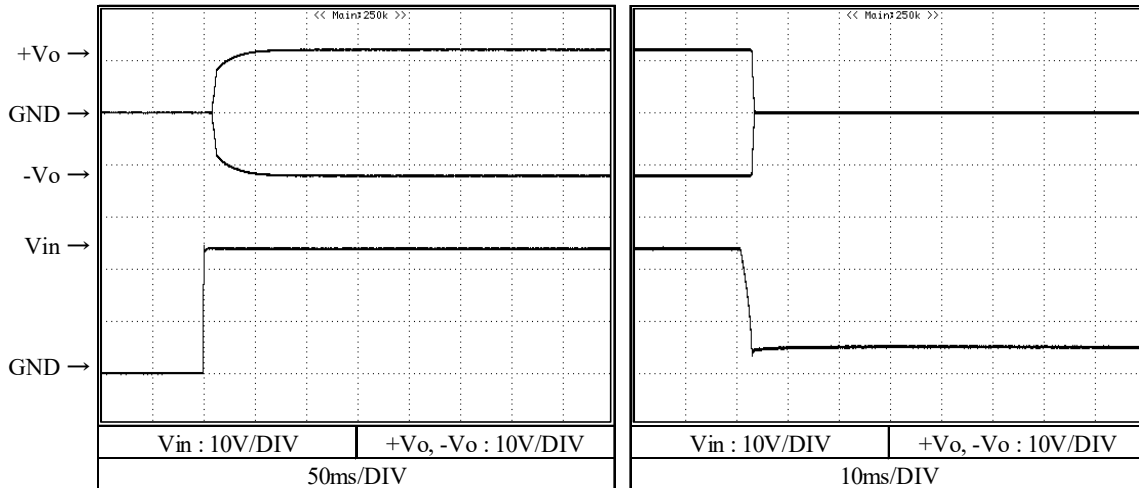




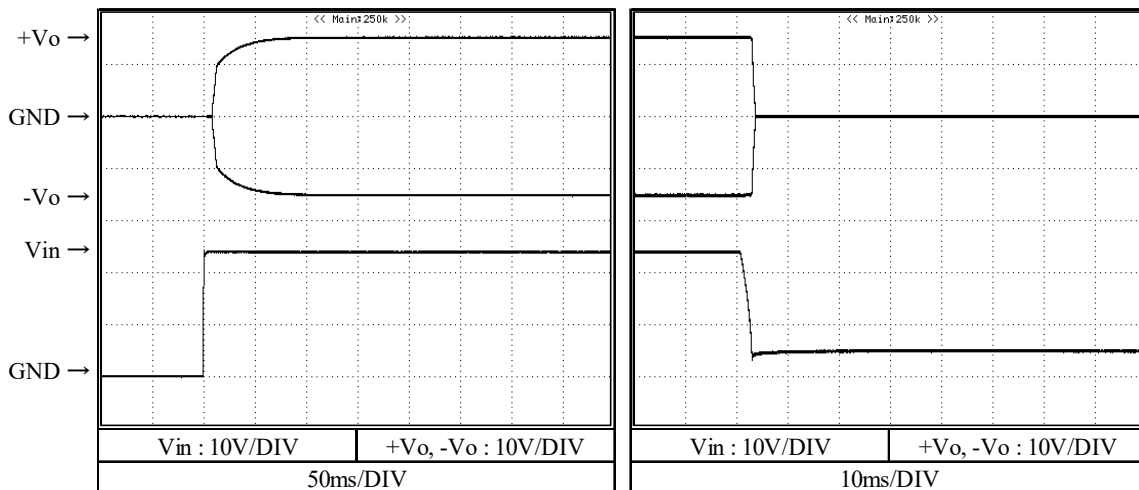
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 24 VDC  
 Io : 100 %  
 Ta : 25 °C

±12V



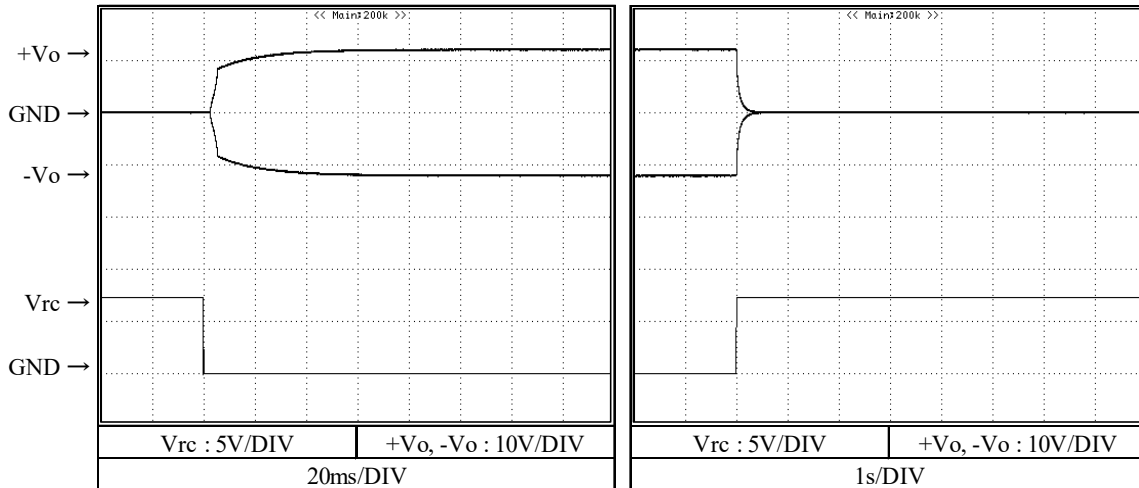
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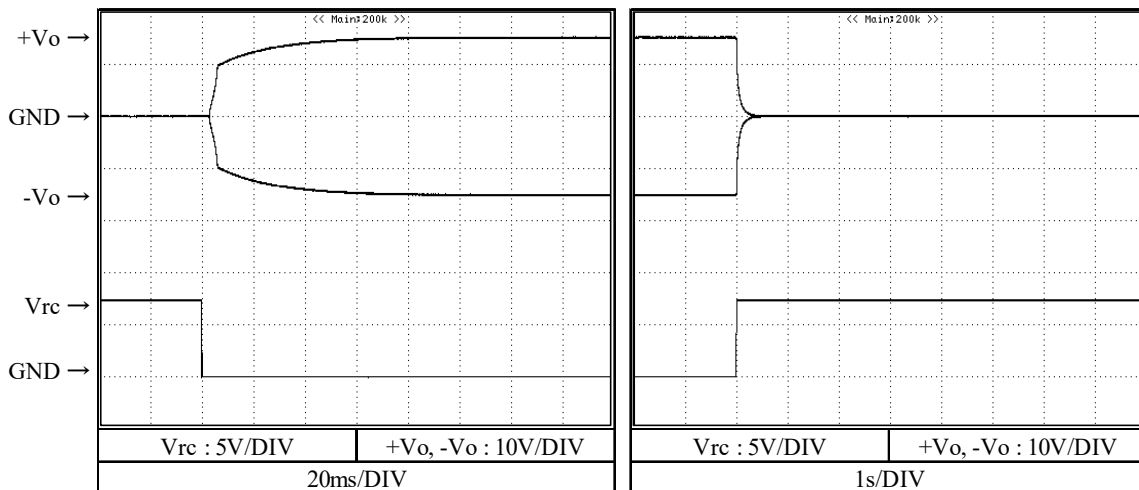
2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)  
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 24 VDC  
Io : 0 %  
Ta : 25 °C

±12V



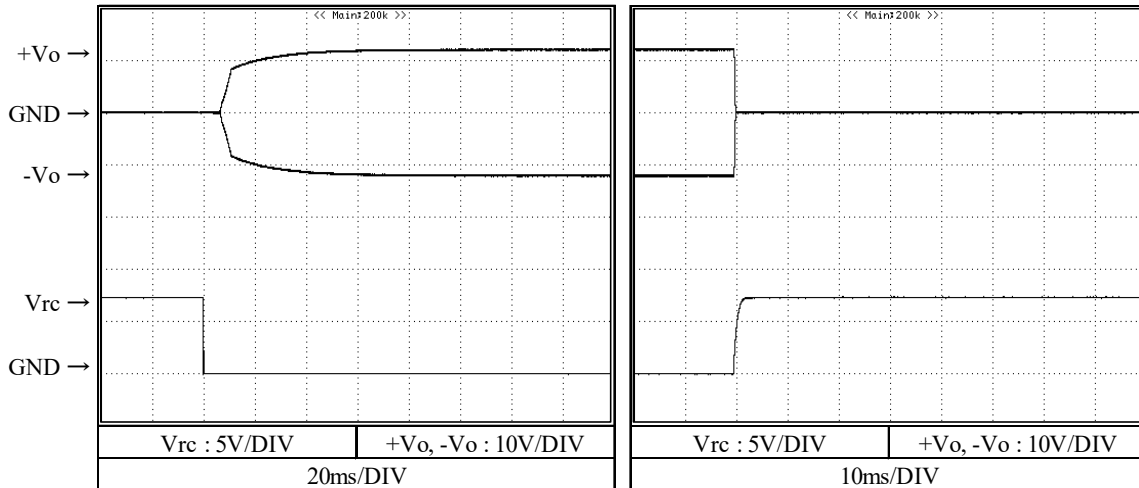
±15V



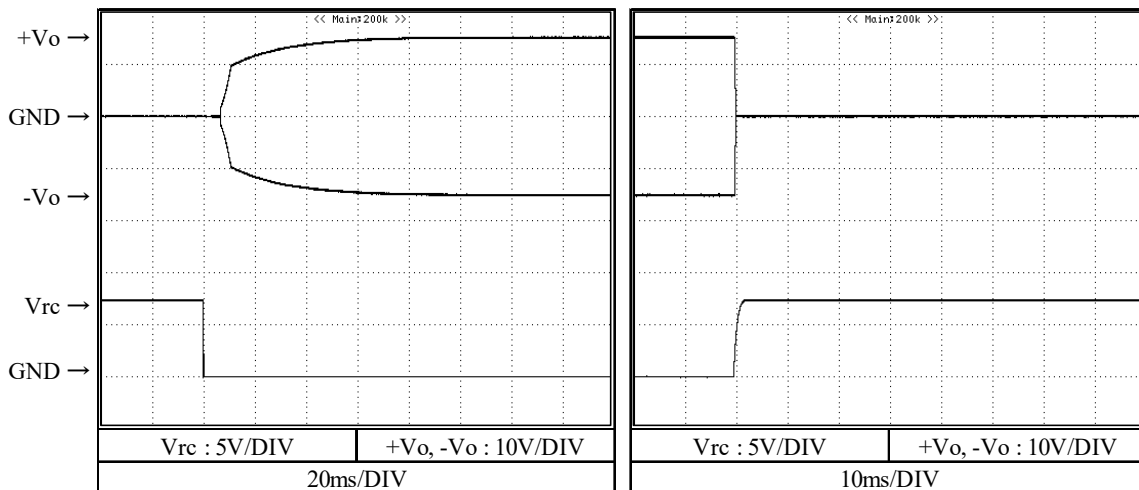
2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)  
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 24 VDC  
Io : 100 %  
Ta : 25 °C

±12V



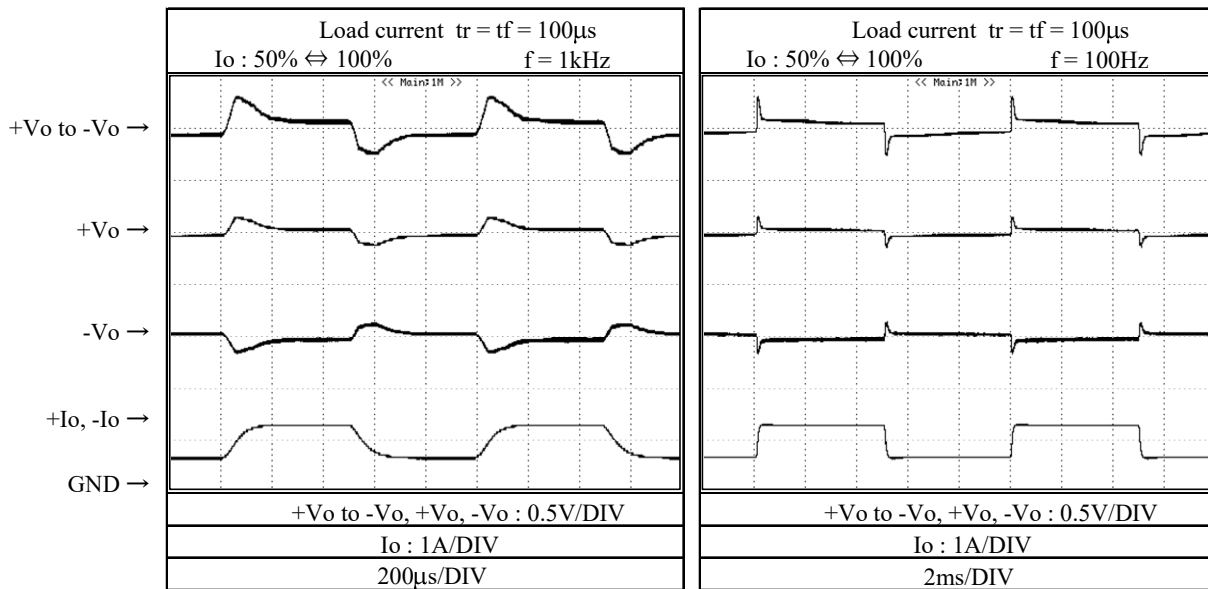
±15V



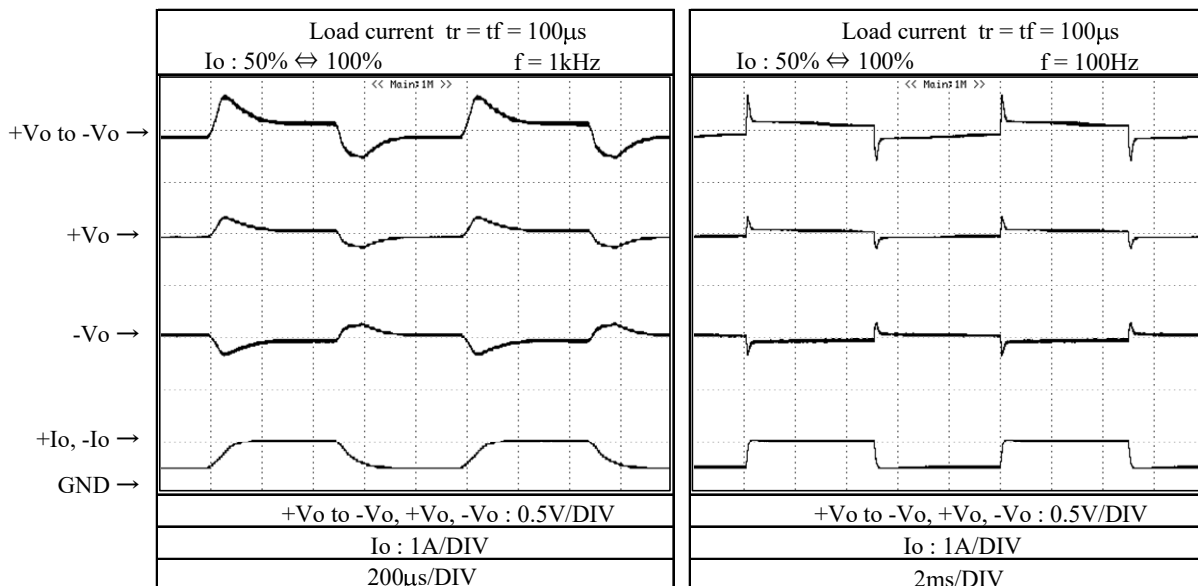
2-6. 過渡応答(負荷急変)特性 Dynamic load response characteristics

Conditions Vin : 24 VDC  
Ta : 25 °C

±12V



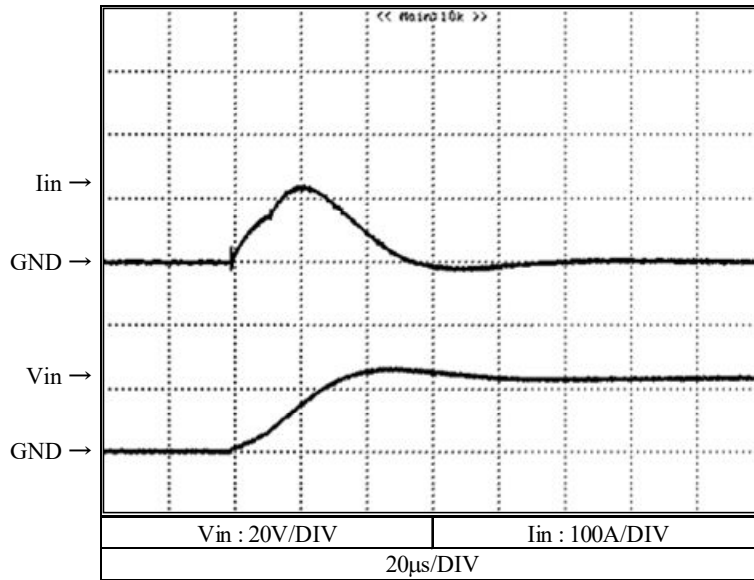
±15V



2-7. 入力サージ電流(突入電流)特性 Inrush current characteristics

Conditions Vin : 24 VDC  
 Io : 100 %  
 Ta : 25 °C

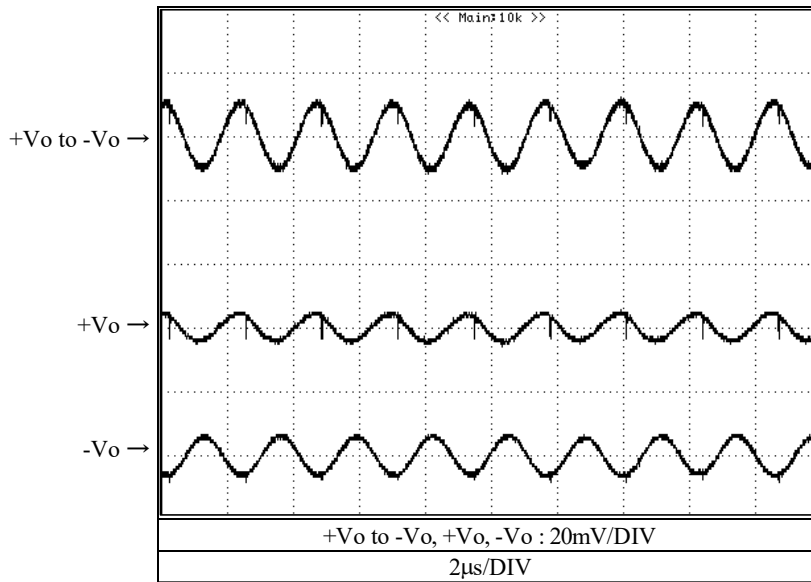
±12V



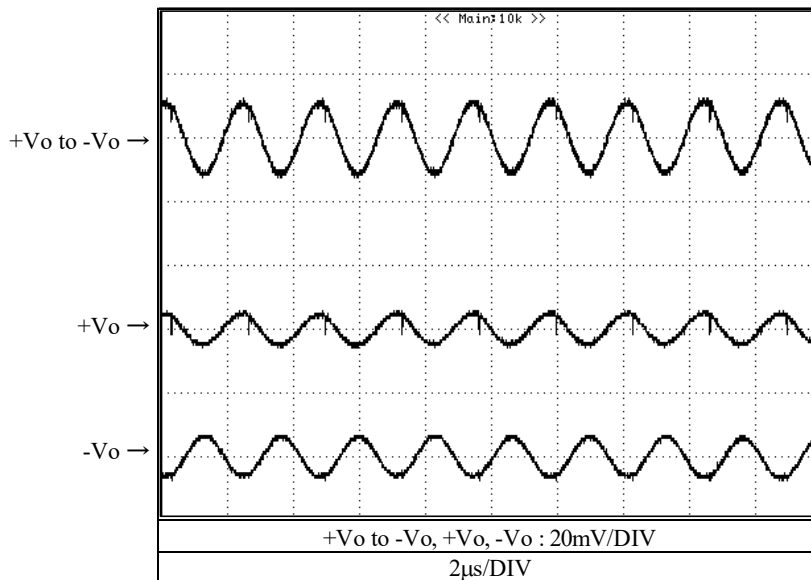
2-8. 出力リップル、ノイズ波形 Output ripple and noise waveform

Conditions Vin : 24 VDC  
 Io : 100 %  
 Ta : 25 °C

±12V



±15V

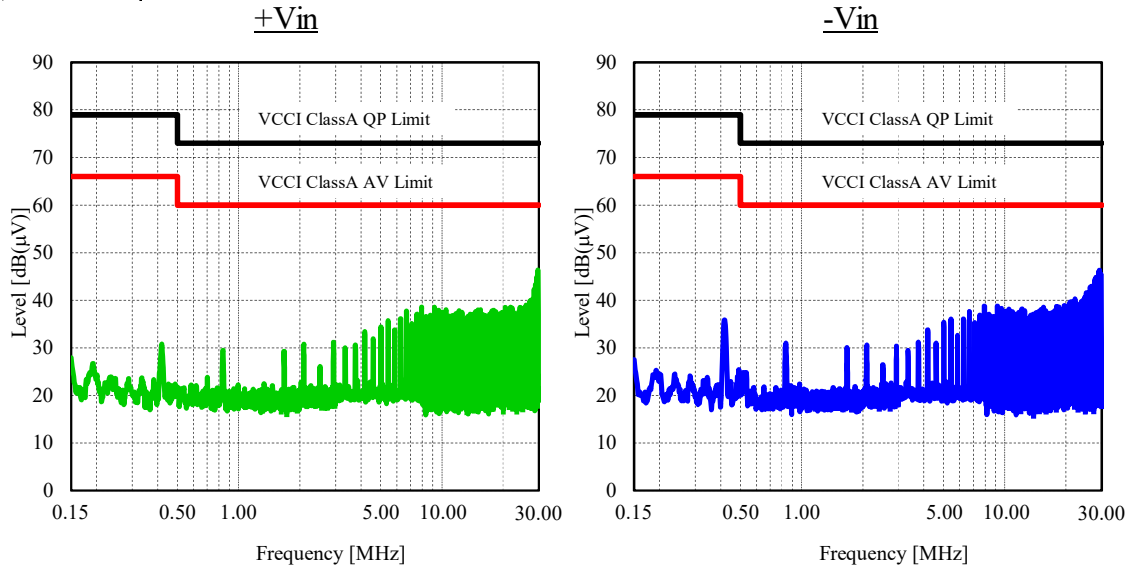


2-9. EMI特性 Electro-Magnetic Interference characteristics

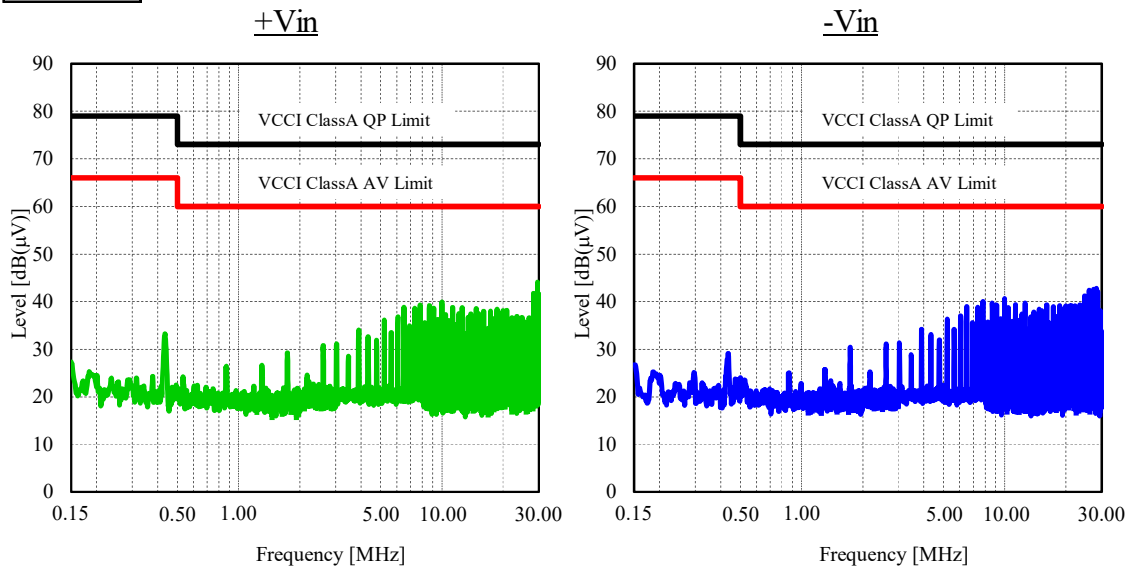
(a) 雑音端子電圧 (帰還ノイズ) Conducted Emission Noise

Conditions Vin : 24 VDC  
Io : 100 %  
Ta : 25 °C

±12V



±15V

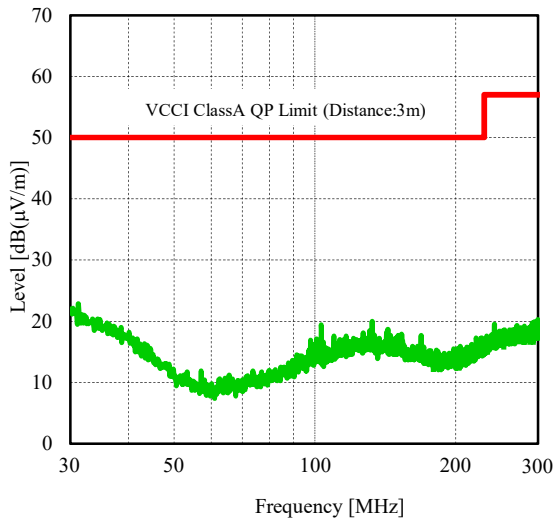


2-9. EMI特性 Electro-Magnetic Interference characteristics  
 (b) 雑音電界強度 (輻射ノイズ) Radiated Emission Noise

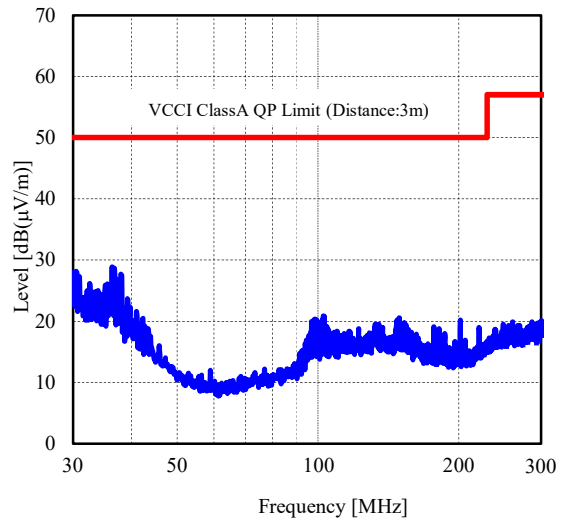
Conditions Vin : 24 VDC  
 Io : 100 %  
 Ta : 25 °C

±12V

HORIZONTAL

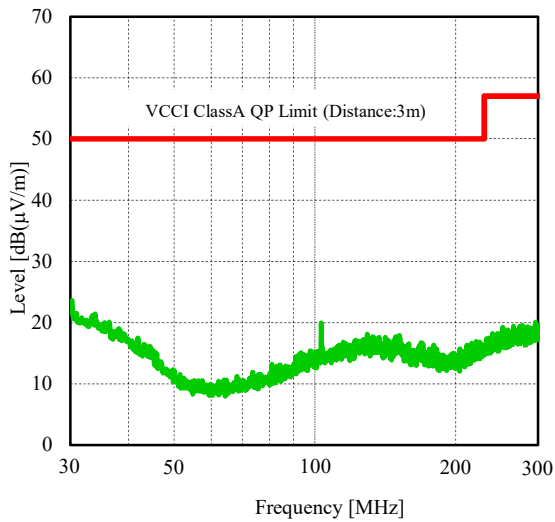


VERTICAL



±15V

HORIZONTAL



VERTICAL

